

2SB1495,Q(J

2SB1495,Q(J Information

whythelsensecom	Part Number	2SB1495,Q(J
	Manufacturer	Toshiba Semiconductor and Storage
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
	Description	TRANS PNP 3A 100V TO220-3
	Package	TO-220-3 Full Pack
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2SB1495,Q(J Specifications

Manufacturer Part Number	2SB1495,Q(J
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-220-3 Full Pack
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	3A
Voltage - Collector Emitter Breakdown (Max)	100V
Vce Saturation (Max) @ Ib, Ic	1.5V @ 1.5mA, 1.5A
Current - Collector Cutoff (Max)	10µA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	2000 @ 2A, 2V
Power - Max	2W
Frequency - Transition	-
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3 Full Pack
Supplier Device Package	TO-220NIS
	Report errors?

2SB1495,Q(J Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

2SB1495,Q(J Payment Methods





If you have any question about 2SB1495,Q(J, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com